NSN 5961-00-901-5534

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass and metal
Overall Length:
Between 0.734 inches and 0.766 inches
Overall Diameter:
Between 0.215 inches and 0.220 inches
End Application:
An/spn-41, 41a and an/trn-28; forrestal class cv; iff aims mk xii; an/blq-10; tarawa class lha; nimitz class cv; wasp class lhd; submarine
surveillance systems
Mounting Method:
Press fit
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
Ku-band equipment; weapon system essential
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
1 binding post and 1 pin
Specification Data:
81349-mil-s-19500/130 government specification
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
A110a0